NSN 5961-00-145-3357

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-145-3357

Inclosure Material:

Metal

Overall Length:

0.165 inches

Overall Height:

0.260 inches

Overall Width:

0.810 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

50.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, with specified resistance

between base and emitter and 3.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

500.00 microamperes zero-gate-voltage source current preset

Maximum Operating Tempurature Per Measurement Point:

71.0 degrees celsius ambient air

Special Features:

Min. Voltage; junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0